

Revision 0.50

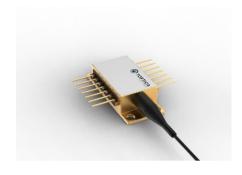
2024-10-25

# **SINGLE FREQUENCY LASER External Cavity Diode Laser**



	Information

Product	Application
780 nm mini-ECDL Laser	Spectroscopy (Rb D2 line)
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	Quantum Technology
with integrated $\mu$ -Isolator and PM Fiber	



## Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T <sub>C</sub>	°C	-40		85
Operational Temperature at Chip	$T_{chip}$	°C	0		50
Forward Current	I <sub>F</sub>	mA			200
Reverse Voltage	$V_{R}$	V			2
Output Power	$P_{opt}$	mW			30
TEC Current	I <sub>TEC</sub>	Α			1.8
TEC Voltage	$V_{TEC}$	V			3.2

### Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

### Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{case}$	°C	-20		65
Operational Temperature at Chip	$T_{chip}$	°C	5		45
Forward Current	I <sub>F</sub>	mA			180
Output Power	P <sub>opt</sub>	mW	5		25

Measurement Conditions / Comments
measured by integrated Thermistor

### Characteristics = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	779	780	781
Target Wavelength	$\lambda_{\mathrm{T}}$	nm		780.24	
Linewidth	Δλ	MHz		0.1	0.3
Mode-hop free Tuning Range	$\Delta \lambda_{tune}$	pm		15	
Output Power	$P_{opt}$	mW			25
Sidemode Suppression Ratio	SMSR	dB	30	45	
Temp. Coefficient of Wavelength	$d\lambda/dT$	nm/K		0.008	
Current Coefficient of Wavelength	dλ / dl	nm/mA		0.001	

Measurement Conditions / Comments
reached within TLD = 5° C 45° C
measured in the time scale of 1 ms
By current tuning, at target wavelength

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Monitor Diode

Thermoelectric Cooler

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Characteristics	= 25° C at BOL	
Parameter	Symbol Unit min	typ max
Laser Current	I <sub>LD</sub> mA	180
Slope Efficiency	η mW/mA	0.3
Threshold Current	I <sub>th</sub> mA	70
Polarization Extinction Ratio	PER dB	20

Measurement Conditions / Comments	

Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>op</sub>	μΑ/mW		2	

Measurement Conditions / Comments
5 V

Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	Α		0.4	
Voltage	$U_TEC$	V		1.5	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0.5	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments	
Popt = 25 mW, ΔT = 20 K	
Popt = 25 mW, ΔT = 20 K	
Popt = 25 mW, ΔT = 20 K	
Popt = 25 mW, ΔT =  Tcase - TLD	

Thomason (Grandard 1410 Typo)	
Parameter	Symbol
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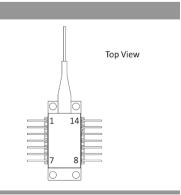
Thermistor (Standard NTC Type)

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	Α		1	.1293 x 10 <sup>-3</sup>	3
Steinhart & Hart Coefficient B	В		2	2.3410 x 10 <sup>-</sup>	4
Steinhart & Hart Coefficient C	С		8	3.7755 x 10 <sup>-1</sup>	3

Measurement Conditions / Comments	
Tchip = 25° C	
$R_1/R_2 = e^{A}(1/T_1 - 1/T_2)$ at Tchip = 0° 50° C	
$1/T = A + B(\ln R) + C(\ln R)^3$	
T: Temperature in Kelvin	
R: resistance at T in $\Omega$	

Pin	Accidnment
	Assignment

1 Thermoelectric Cooler (+)	14 Thermoelectric Cooler (-)
2 Thermistor	13 Case
3 Photo Diode Anode	12 not connected
4 Photo Diode Cathode	11 Laser Diode Cathode
5 Thermistor	10 Laser Diode Anode
6 not connected	9 not connected
7 not connected	8 not connected



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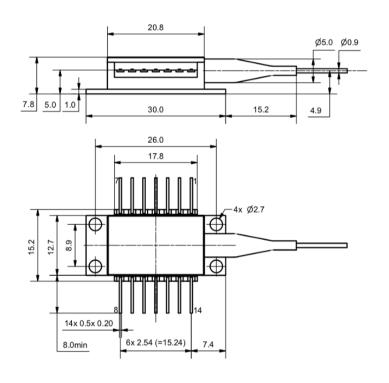


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## SINGLE FREQUENCY LASER **External Cavity Diode Laser**

## Package Drawings





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Fiber and	Connector	i voe i	OULDUL

Parameter	
PM Fiber	900 / 125 / 5.5 μm, UV/Polyester-elastomer Coating (I = 1 +/-0.1 m)
Connector	FC/APC (narrow key / 2mm)

Measurement Conditions / Comments

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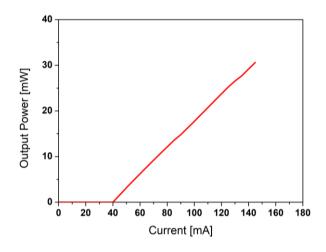
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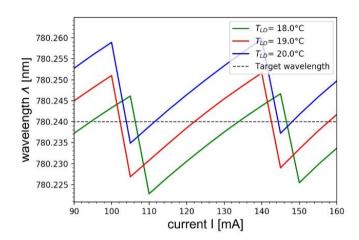
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## **SINGLE FREQUENCY LASER External Cavity Diode Laser**

#### **Typical Measurement data**





#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.





A laser diode is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.



IEC-60825-1

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.





Complies with 21 CFR 1040.10 and 1040.40

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

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